

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: IWASAKI et al.  
Serial No.: (New Continuation Application under 37 CFR §1.53(b) of  
U.S. Application Serial No. 09/787,528)  
Filed: July 3, 2003  
For: SEMICONDUCTOR DEVICE  
Group: 2813  
Examiner: S. Smoot

**PRELIMINARY AMENDMENT**

**MS: PATENT APPLICATIONS**

Commissioner For Patents  
Post Office Box 1450  
Alexandria, VA 22313-1450

July 3, 2003

Sir:

Prior to examination, please amend the above-identified application as follows:

In the Title:

**PLEASE AMEND THE TITLE TO READ AS FOLLOWS:**

**SEMICONDUCTOR DEVICE WITH MULTILAYER CONDUCTIVE  
STRUCTURE FORMED ON A SEMICONDUCTOR SUBSTRATE.**